



# WT772

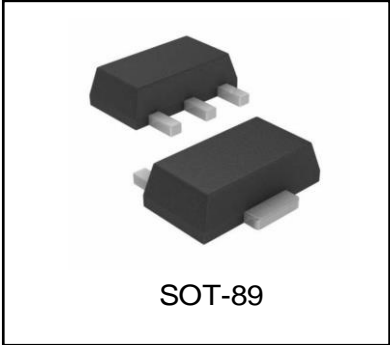
## PNP Silicon Transistor

### Features

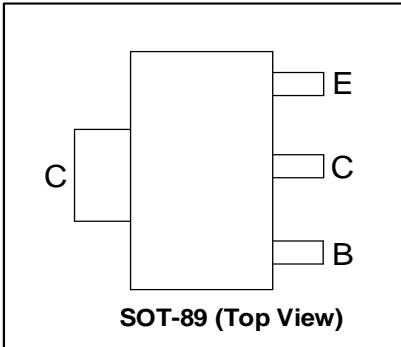
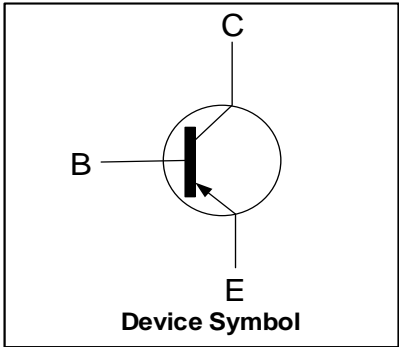
- Low Speed Switching

### Mechanical Characteristics

- SOT-89 Package
- Marking : Making Code
- RoHS Compliant



### Schematic & PIN Configuration



### Absolute Maximum Rating

Parameter	Symbol	Value	Unit
Collector Base Voltage	$V_{CBO}$	-40	V
Collector Emitter Voltage	$V_{CEO}$	-30	V
Emitter Base Voltage	$V_{EBO}$	-6	V
Collector Current	$I_C$	-3	A
Collector Power Dissipation	$P_C$	500	mW
Junction Temperature	$T_j$	150	°C
Storage Temperature	$T_{stg}$	-55 ~ 150	°C
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	250	°C/W

**Electrical Characteristics (T<sub>amb</sub>=25°C unless otherwise noted)**

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> = -100μA, I <sub>E</sub> = 0	-40	-	-	V
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> = -10mA, I <sub>B</sub> = 0	-30	-	-	V
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> = -100μA, I <sub>C</sub> = 0	-6	-	-	V
Collector Cut-off Current	I <sub>CBO</sub>	V <sub>CB</sub> = -40V, I <sub>E</sub> = 0	-	-	-1	μA
Collector Cut-off Current	I <sub>CEO</sub>	V <sub>CE</sub> = -30V, I <sub>B</sub> = 0	-	-	-10	μA
Emitter Cut-off Current	I <sub>EBO</sub>	V <sub>EB</sub> = -6V, I <sub>C</sub> = 0	-	-	-1	μA
DC Current Gain	h <sub>FE(1)</sub>	V <sub>CE</sub> = -2V, I <sub>C</sub> = -1A	200	-	400	-
	h <sub>FE(2)</sub>	V <sub>CE</sub> = -2V, I <sub>C</sub> = -100mA	32	-	-	-
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> = -2A, I <sub>B</sub> = -0.2A	-	-	-0.45	V
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> = -2A, I <sub>B</sub> = -0.2A	-	-	-1.50	V
Transition Frequency	f <sub>T</sub>	V <sub>CE</sub> = -5V, I <sub>C</sub> = -0.1A, f=10MHz	50	-	-	MHz

**Typical Characteristics**

Figure 1. Static Characteristics

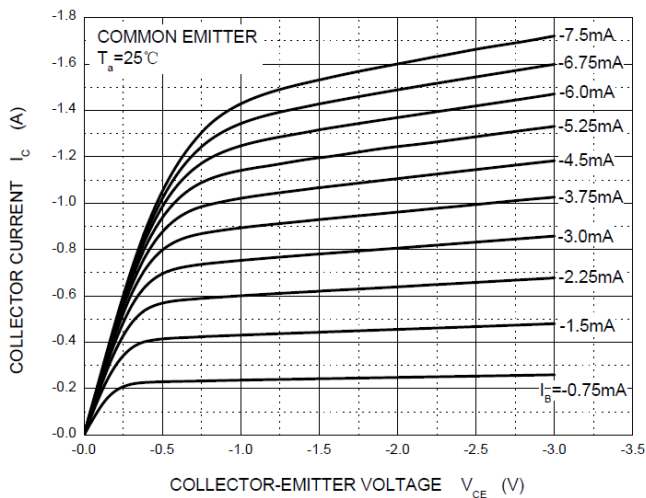


Figure 3. V<sub>CE(sat)</sub> vs. I<sub>C</sub>

Figure 2. h<sub>FE</sub> vs. I<sub>C</sub>

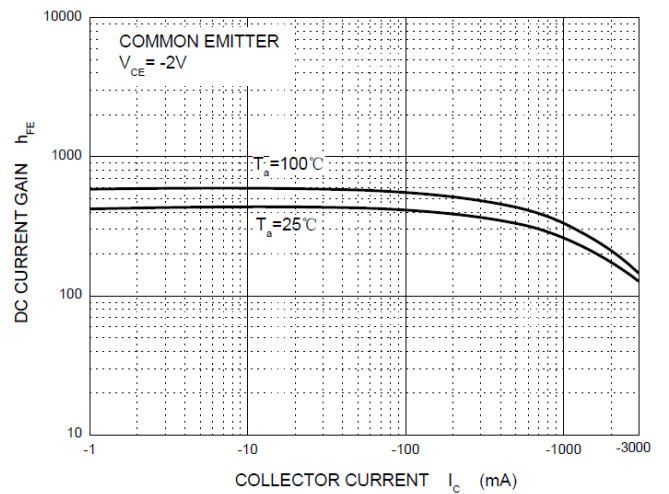


Figure 4. V<sub>BE(sat)</sub> vs. I<sub>C</sub>

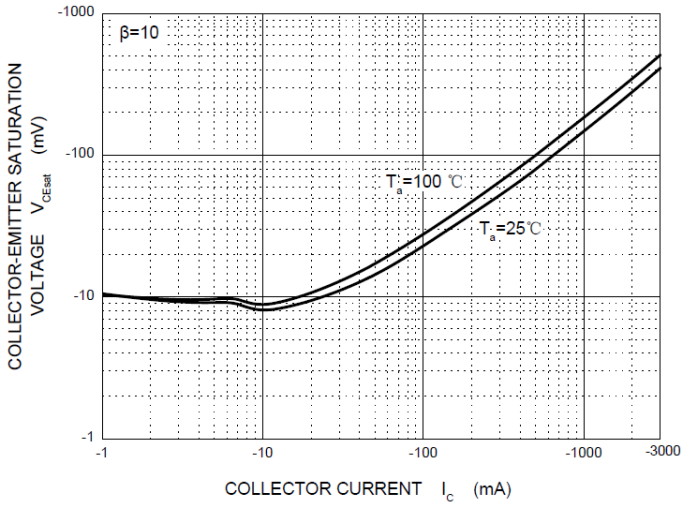


Figure 5.  $I_c$  vs.  $V_{BE}$

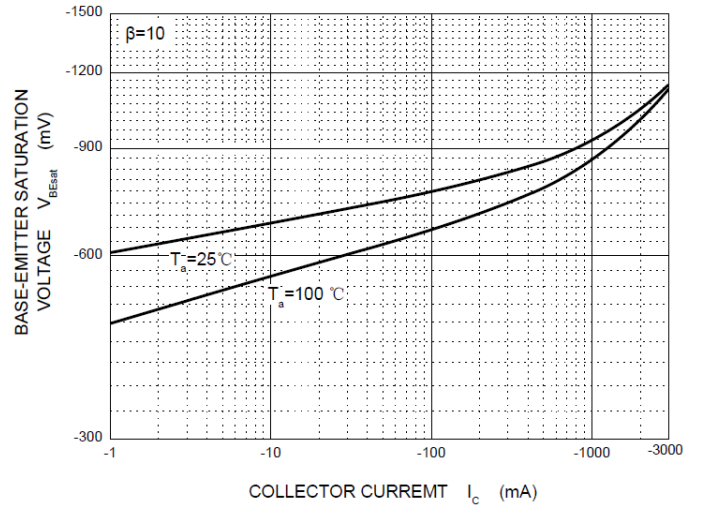


Figure 6.  $f_T$  vs.  $I_c$

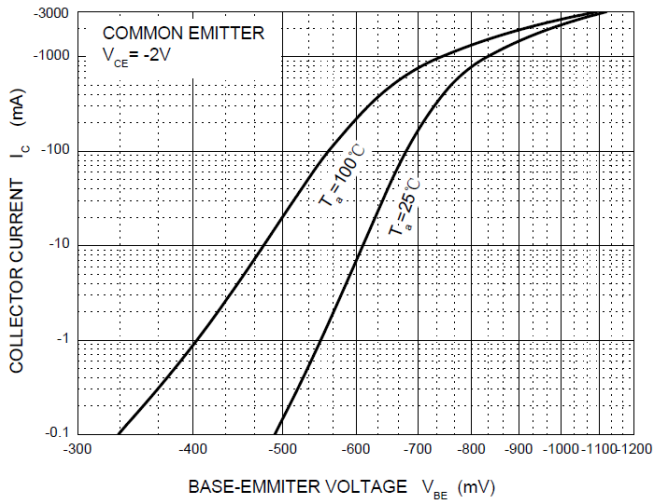
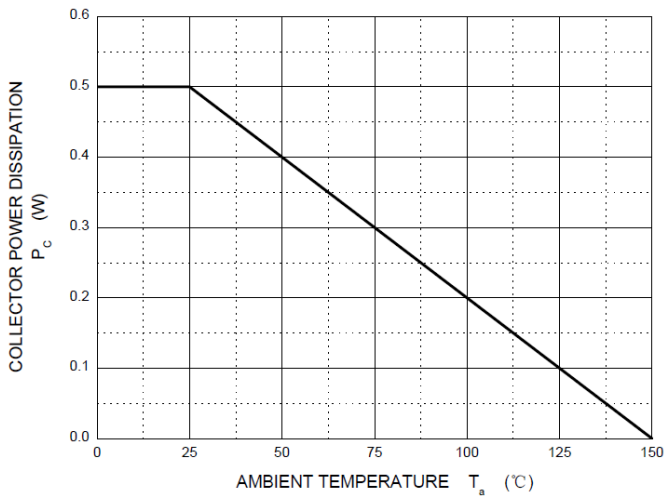
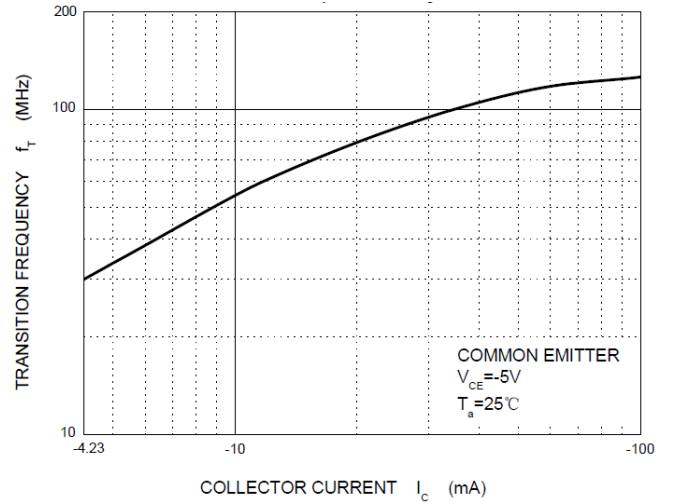
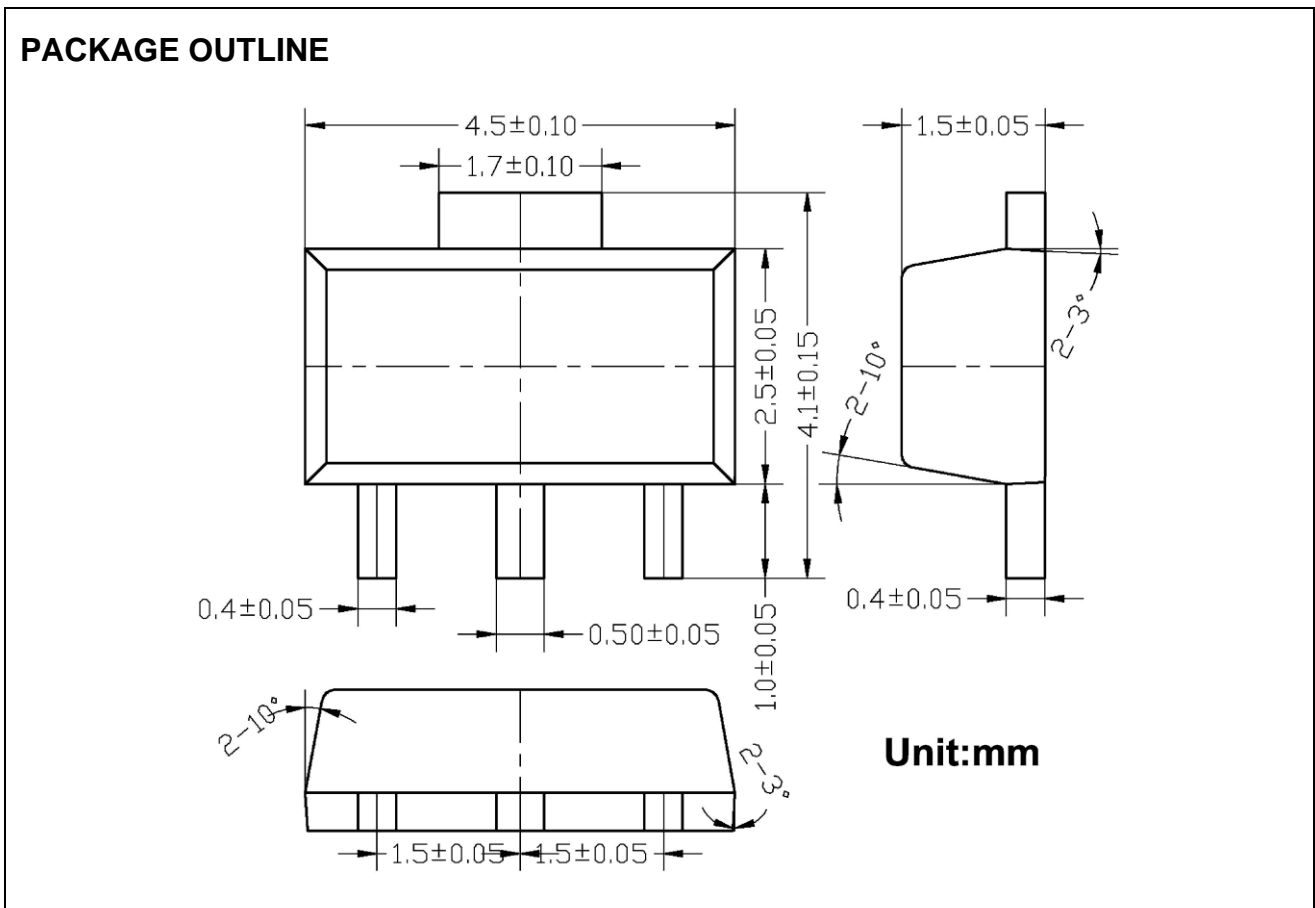


Figure 7.  $P_C$  vs.  $T_a$



Outline Drawing – SOT-89



Marking Codes

Part Number	WT772
Marking Code	

Package Information

Qty: 1k/Reel

CONTACT INFORMATION

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For additional information, please contact your local Sales Representative.

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*Specifications are subject to change without notice.  
The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time.  
Users should verify actual device performance in their specific applications.*